Ferromagnetic resonance linewidth in ultrathin films with perpendicular magnetic anisotropy

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Transition-metal ferromagnetic films with perpendicular magnetic anisotropy (PMA) have ferromagnetic resonance (FMR) linewidths that are one order of magnitude larger than soft magnetic materials, such as pure iron (Fe) and Permalloy (NiFe) thin films. A broadband FMR setup has been used to investigate the origin of the enhanced linewidth in a material in which the PMA could be systematically reduced by irradiation with Helium ions: Ni/Co multilayers. The FMR linewidth depends linearly on frequency for perpendicular applied fields and increases significantly when the magnetization is rotated into the film plane. Irradiation of the film with Helium ions decreases the PMA and the distribution of PMA parameters, leading to a large reduction in the FMR linewidth for in-plane magnetization. These results suggest that fluctuations in PMA lead to a large two magnon scattering contribution to the linewidth for in-plane magnetization and establish that the Gilbert damping is enhanced in such materials ($\alpha$ = 0.04, compared to $\alpha$ = 0.002 for pure Fe).

Magnetic materials with perpendicular magnetic anisotropy (PMA) are of great interest in information storage technology, offering the possibility of smaller magnetic bits1 and more efficient magnetic random access memories based on the spin-transfer effect.2 They typically are multilayers of transition metals (e.g., Co/Pt, Co/Pd, and Ni/Co) with strong interface contributions to the magnetic anisotropy3 that render them magnetically hard. In contrast to soft magnetic materials which have been widely studied and modeled,4–7 such films are poorly understood. Experiments indicate that there are large distributions in their magnetic characteristics, such as their switching fields.1 An understanding of magnetization relaxation in such materials is of particular importance since magnetization damping determines the performance of magnetic devices, such as the time scale for magnetization reversal and the current required for spin-transfer-induced switching.2,8

Ferromagnetic resonance (FMR) spectroscopy provides information on the magnetic damping through study of the linewidth of the microwave absorption peak, $\Delta H$, when the applied field is swept at a fixed microwave frequency. FMR studies of thin films with PMA show very broad linewidths, several 10 s of mT at low frequencies ($\approx$10 GHz) for polycrystalline alloy,9 multilayer,10 and even epitaxial thin films.11 This is at least one order of magnitude larger than the FMR linewidth for in-plane magnetization. These results suggest that fluctuations in PMA lead to a large two magnon scattering contribution to the linewidth for in-plane magnetization and establish that the Gilbert damping is enhanced in such materials ($\alpha$ = 0.04, compared to $\alpha$ = 0.002 for pure Fe).

The inhomogeneous contribution is associated with disorder. First, fluctuations in the materials magnetic properties, such as its anisotropy or magnetization, lead to a linewidth that is frequency independent; in a simple picture, independent parts of the sample come into resonance at different applied magnetic fields. Second, disorder can couple the uniform precessional mode ($k$ = 0), excited in an FMR experiment, to degenerate finite-$k$ ($k$ ≠ 0) spin-wave modes. This mechanism of relaxation of the uniform mode is known as two magnon scattering (TMS).13 TMS requires a spin-wave dispersion with finite-$k$ modes that are degenerate with the $k$ = 0 mode that only occurs for certain magnetization orientations.

In this Rapid Communication we present FMR results on ultrathin Ni/Co multilayer films and investigate the origin of the broad FMR lines in films with PMA. Ni/Co multilayers were deposited between Pd/Co/Pd layers that enhance the PMA and enable large variations in the PMA with helium ion irradiation. These films were sectioned into several micrometers thick pieces, which were then irradiated with 800 KeV Helium ions in a raster pattern, where the ion flux, the number of ions per incident spot, and the distance between spots were varied to keep the total number of ion impacts per unit area constant. The FMR linewidths in the non-irradiated film were 30 mT, which increased to over 100 mT at a low irradiation fluence of 1011 ions/cm². The linewidths increased steeply with fluence and saturated for fluences greater than 1012 ions/cm². Irradiation also reduces the in-plane PMA, as evidenced by a shift in the resonance field at a fixed frequency and a decrease in the FMR linewidth when the applied magnetic field is swept at a fixed microwave frequency. These results indicate that fluctuations in PMA lead to a large two magnon scattering contribution to the linewidth for in-plane magnetization and establish that the Gilbert damping is enhanced in such materials ($\alpha$ = 0.04, compared to $\alpha$ = 0.002 for pure Fe).

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irradiation.\textsuperscript{14} The films are \(13\) nm Ta\(1\) nm Pd\(0.8\) nm Co\(0.14\) nm Co\(3\) nm Pd\(0.2\) nm Co\(3\) nm Ta deposited on a Si-SiN wafers using dc magnetron sputtering and were irradiated with \(20\) keV He\(^+\) ions at a fluence of \(10^{15}\) ions/cm\(^2\). The He\(^+\) ions induce interatomic displacements that intermix the Ni-Co interfaces leading to a reduction in interface anisotropy and strain in the film. The magnetization was measured at room temperature with a SQUID magnetometer and found to be \(M_s = 4.75 \times 10^5\) A/m. The saturation magnetization does not change by more than 10\% upon irradiation, which is in the range of the magnetometry measurements accuracy.

FMR studies were conducted from 4 to 40 GHz at room temperature with a coplanar waveguide as a function of the field angle with respect to the film plane. The absorption signal was recorded by sweeping the magnetic field at constant frequency.\textsuperscript{15} FMR measurements were performed on a virgin film (not irradiated) and on an irradiated film.

Figure 1(a) shows the frequency dependence of the resonance field when the applied field is perpendicular to the film plane. The \(x\) intercept enables determination of the PMA and the slope is proportional to the gyromagnetic ratio. We take the magnetic energy density to be:

\[
E = -\mu_0 M \cdot H + \frac{1}{2} \mu_0 M_s^2 \sin^2 \phi - (K_1 + 2K_2) \sin^2 \phi + K_2 \sin^4 \phi. \tag{3}
\]

The first term is the Zeeman energy, the second term is the magnetostatic energy, and the last two terms include the first and second-order uniaxial PMA constants, \(K_1\) and \(K_2\). Taking \(\mu_0 H_{\text{eff}} = -\partial E / \partial M\) in Eq. (1) the resonance condition is

\[
f = \frac{\gamma}{2\pi} \left( \mu_0 H_{\text{res}} - \mu_0 M_s + \frac{2K_1}{M_s} \right). \tag{4}
\]

From the \(x\) intercepts in Fig. 1(a), \(K_1 = (1.93 \pm 0.07) \times 10^8\) J/m\(^3\) for the virgin film and \((1.05 \pm 0.02) \times 10^5\) J/m\(^3\) for the irradiated film; helium irradiation reduces the magnetic anisotropy by a factor of two. Note that in the irradiated film the \(x\) intercept is positive \((\mu_0 M_s > 2K_1/M_s)\). This implies that the easy magnetization direction is in the film plane. The angular dependence of \(H_{\text{res}}\) (Fig. 1(b)) also illustrates this: the maximum resonance field shifts from in-plane to out of plane on irradiation. The gyromagnetic ratio is not significantly changed \(\gamma = 1.996 \pm 0.009 \times 10^{11}\) 1/(T s) for the virgin film and \(\gamma = 1.973 \pm 0.004 \times 10^{11}\) 1/(T s) for the irradiated film (i.e., \(g = 2.24 \pm 0.01\)). The second order anisotropy constant \(K_2\) was obtained from a fit of the angular dependence of the resonance field, for magnetization angles \(\phi\) between 45\(^\circ\) and 90\(^\circ\). This angular range was selected because TMS is not operative (see below) and therefore does not affect the resonance position in this range. For the virgin film, \(K_2 = 0.11 \times 10^2\) J/m\(^3\). Note that when \(K_2\) is set to zero, \(\chi^2\) of the fit increases by a factor 30. For the irradiated film, \(K_2 = 0.03 \times 10^2\) J/m\(^3\). Hence \(K_2\) decreases upon irradiation and remains much smaller than \(K_1\). The solid line in Fig. 1(b) is the resulting fit. When the field approaches the in-plane direction, the measured resonance field is higher than the fit. The shift is of the order of 0.1 T for the virgin film and 0.025 T for the irradiated film. It is frequency dependent; increasing with frequency. This shift will be discussed further below.

Figure 2(a) shows the frequency dependence of the linewidth (FWHM) for two directions of the applied field. \(\Delta H^\perp\) of the virgin film increases linearly with frequency consistent with Gilbert damping. Fitting to Eq. (2), we find \(\alpha = 0.044 \pm 0.003\) and \(\mu_0 \Delta H_0^\perp = 15.6 \pm 3.6\) mT. When the field is applied in the film plane, the linewidth is significantly larger. \(\Delta H^\parallel\) decreases with increasing frequency for \(f \approx 10\) GHz and then is practically independent of frequency at \(f = 140 \pm 20\) mT. However, for the irradiated film, the linewidth varies linearly with frequency both for in-plane and out-of-plane applied fields, with nearly the same slope. The Gilbert damping is \(\alpha = 0.039 \pm 0.004\). Note that \(\mu_0 \Delta H_0^\parallel\) is larger than \(\mu_0 \Delta H_0^\perp\) by about 15 mT.

The angular dependence of the linewidth at 20 GHz is shown in Fig. 3. The linewidth of the virgin film decreases significantly with increasing field angle up 30\(^\circ\) and then is
nearly constant, independent of field angle. The linewidth of the irradiated film is nearly independent of the field angle with a relatively small enhancement of ~15 mT close to the in-plane direction. We fit this data assuming that the inhomogeneous broadening of the line is associated mainly with spatial variations in the PMA, specifically local variation in spatial stiffness and $t$ is the film thickness. $\phi_0$ is the direction of propagation of the spin-wave in the film plane relative to the in-plane projection of the magnetization. The inset of Fig. 4 shows the dispersion relation for the virgin and the irradiated film for an in-plane applied field at 20 GHz. For the virgin film, with the easy axis normal to the film plane ($M_{\text{eff}}^r < 0$) there are degenerate modes available in all directions in $k$ space. For the irradiated film ($M_{\text{eff}}^r > 0$) degenerate modes are only available when $\phi_0 \approx 74^\circ$.

The spin-wave density of states (DOS), determined from Eq. (5), is shown as a function of field angle in Fig. 4 at 20 GHz. The DOS of the virgin film is two times larger than that of the irradiated film at $\phi_0 = 0$. Note that for both films, the DOS vanishes at a critical field angle that corresponds to a magnetization angle $\phi = 45^\circ$. For the virgin film, the enhancement of $\Delta H$ occurs at $\phi_0 = 30^\circ$ [Fig. 3(a)] at the critical angle seen in Fig. 4.

The TMS linewidth depends on the density of states and the disorder, which couples the modes:

$$\Delta H_{\text{TMS}} = \left(\frac{\partial H_{\text{res}}}{\partial \omega}\right) \left| A_0 \right|^2 \int C_\xi(\xi) \delta(\omega_2 - \omega_0) dk,$$

where $A_0$ is a scattering amplitude. $C_\xi(\xi) = 2\pi \xi^2/[1 + (k\xi)^2]^{1/2}$ is a correlation function, where $\xi$ is correlation length, the typical length scale of disorder. Equation (7) is valid in the limit of weak disorder.

We assume that the disorder of our films is associated with spatial variations in the PMA, $K_1$. Then the magnetic energy density varies as $\Delta E(r) = -k_1(r) M_s^2/M_s^2$, and the scattering probability is

$$\left| A_0 \right|^2 = \frac{\gamma}{4\omega_0^2} \left[ B_{10}^2 \sin^4 \phi + B_{20}^2 \cos^2 2\phi - 2(\omega_0/\gamma)^2 \sin^2 \phi \cos 2\phi \right] \left( \frac{2\Delta k_1}{M_s} \right)^2,$$

where $\Delta k_1$ is the rms amplitude of the distribution of PMA, $k_1(r)$. Therefore the TMS linewidth broadening scales as the square of $\Delta k_1$. Since the variations in PMA of the virgin film are larger than that of the irradiated film the linewidth broadening
ening from the TMS mechanism is expected to be much larger in the virgin film, qualitatively consistent with the data.

A best fit of the linewidth data to the TMS model is shown in Fig. 3(a). For the virgin film, we find $\xi = 44$ nm, approximately four times the film grain size, and $\Delta k_0 = 9 \times 10^3$ J/m. The exchange stiffness, $D = 2A/\mu_0 M_s$, with the exchange constant $A = 0.83 \times 10^{-11}$ J/m, is used in the fittings. The cut-off field angle for the enhancement of the field linewidth agrees well with the data [Fig. 3(a)]. For the irradiated film, a similar analysis gives: $\xi = 80 \pm 40$ nm and $\Delta k_0 = (4 \pm 2) \times 10^3$ J/m. For both the virgin film and the irradiated film, $\Delta k_1 > \Delta K_1$. We note that $\Delta K_1$ is determined using a local resonance model in which the film is assumed to be composed of independent (uncoupled) magnetic regions resonating at different fields. In contrast, the TMS model assumes that the magnetic regions with different anisotropies are coupled via exchange and dipolar fields. Therefore, we would expect that $\Delta k_1 > \Delta K_1$ as exchange interactions between magnetic regions with different anisotropies will narrow the resonance lines.

TMS is also expected to shift the resonance position. For applied fields in-plane and $f = 20$ GHz we estimate the resonance field shift to be $\sim 33$ mT. This is smaller than what is observed experimentally ($\sim 93$ mT). The deviations of the fits in Fig. 1(b) may be associated with an anisotropy in the gyromagnetic ratio, i.e., a $g$ that is smaller for $M$ in the film plane. Note that if we assume that the $g$ factor is slightly anisotropic ($\sim 1\%$), we can fit the full angular dependence of the resonance field of the irradiated film.

We note that the TMS model cannot explain the enhanced linewidth for small in-plane applied fields for the virgin film [Fig. 2(a)]. The FMR linewidth increases dramatically when the frequency decreases below about 10 GHz. This enhancement of the linewidth is likely associated with the fact that the magnetization is not saturated in the film plane, i.e., there is a distribution of magnetization angles in the film relative to the applied field direction. In fact, magnetometry measurements at room temperature with the dc field swept in the film plane give a saturation field of $\mu_0 H_{sat} = 0.5$ T, somewhat larger than the effective demagnetization field ($M_{sat} = 0.31$ T). It is for resonance fields less than this value (which correspond to $f < 10$ GHz) that the linewidth increases rapidly.

In sum, these results show that the FMR linewidth in Ni|Co multilayer films is large due to disorder and TMS as well as enhanced Gilbert damping. The latter is an intrinsic relaxation mechanism, associated with magnon-electron scattering and spin relaxation due to spin-orbit scattering. As these materials contain heavy elements such as Pd and short electron lifetimes at the Fermi level, large intrinsic damping rates are not unexpected. The results indicate that the FMR linewidth of Ni|Co multilayers can be reduced through light irradiation and further demonstrate that the Gilbert damping rate is largely unaffected by irradiation. These results, including the reduction in the PMA distribution at high irradiation dose, have important implications for the applications of PMA materials in data storage and spin-electronic applications which require tight control of the anisotropy, anisotropy distributions, and resonant behavior.

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